

SANYO Semiconductors DATA SHEET

An ON Semiconductor Company

30A02MH— Low-Frequency General-Purpose Amplifier Applications

Applications

· Low-frequency Amplifier, high-speed switching small motor drive

Features

- · Large current capacity
- · Low collector-to-emitter saturation voltage (resistance) RCE(sat) typ=580mΩ[IC=0.7A, IB=35mA]
- · Small ON-resistance (Ron)

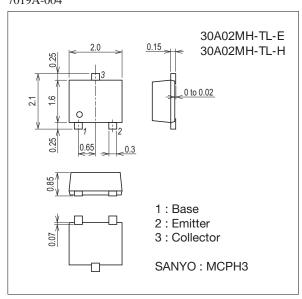
Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	VCBO		-30	V
Collector-to-Emitter Voltage	VCEO		-30	V
Emitter-to-Base Voltage	VEBO		-5	V
Collector Current	IC		-700	mA
Collector Current (Pulse)	ICP		-1.4	А
Collector Dissipation	PC	When mounted on ceramic substrate (600mm ² x0.8mm)	600	mW
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Package Dimensions

unit : mm (typ) 7019A-004

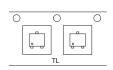


Product & Package Information

• Package : MCPH3

JEITA, JEDEC : SC-70, SOT-323
 Minimum Packing Quantity : 3,000 pcs./reel

Packing Type: TL



Marking



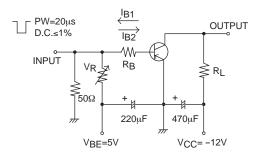
Electrical Connection



Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Linit
	Syllibol	Conditions	min	typ	max	Unit
Collector Cutoff Current	ICBO	V _{CB} = -30V, I _E =0A			-100	nA
Emitter Cutoff Current	IEBO	V _{EB} = -4V, I _C =0A			-100	nA
DC Current Gain	hFE	V _{CE} = -2V, I _C = -10mA	200		500	
Gain-Bandwidth Product	fT	V _{CE} = -10V, I _C = -50mA		520		MHz
Output Capacitance	Cob	V _{CB} = -10V, f=1MHz		4.7		рF
Collector-to-Emitter Saturation Voltage	V _{CE} (sat)	I _C = -200mA, I _B = -10mA		-110	-220	mV
Base-to-Emitter Saturation Voltage	V _{BE} (sat)	I _C = -200mA, I _B = -10mA		-0.9	-1.2	V
Collector-to-Base Breakdown Voltage	V(BR)CBO	I _C = -10μA, I _E =0A	-30			V
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	IC= -1mA, RBE=∞	-30			V
Emitter-to-Base Breakdown Voltage	V(BR)EBO	IE= -10μA, IC=0A	-5			V
Turn-ON Time	ton			35		ns
Storage Time	tstg	See specified Test Circuit.		125		ns
Fall Time	tf			25		ns

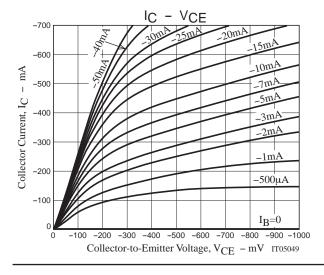
Switching Time Test Circuit

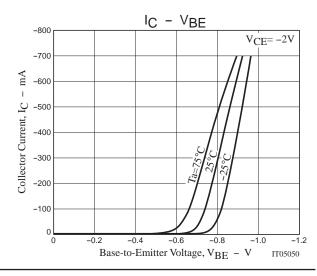


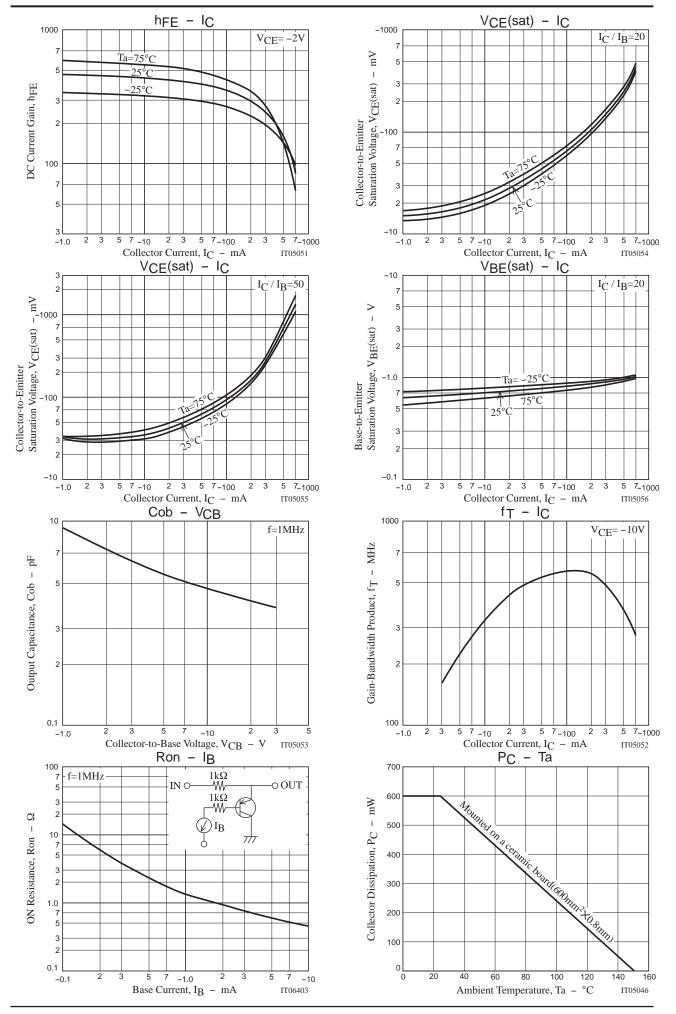
IC=20IB1= -20IB2= -300mA

Ordering Information

Device	Package	Shipping	memo	
30A02MH-TL-E	МСРН3	3,000pcs./reel	Pb Free	
30A02MH-TL-H	MCPH3	3,000pcs./reel	Pb Free and Halogen Free	





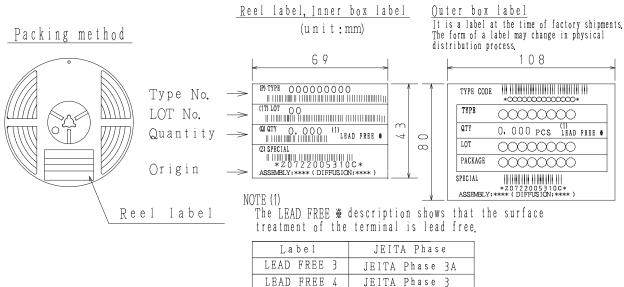


Embossed Taping Specification

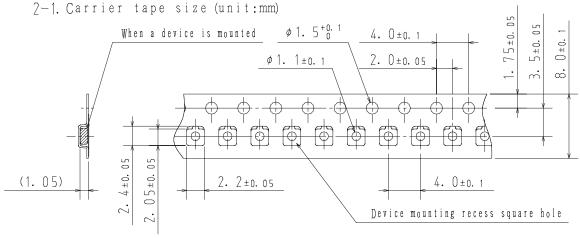
30A02MH-TL-E, 30A02MH-TL-H

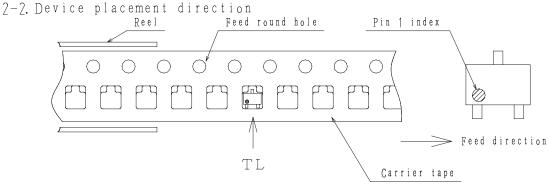
1. Packing Format

Package Name	Carrier Tape	Maximun Number of devices contained (pcs)			Packing	g format	
	Туре	Reel	Inner box	Outer box	Inner BOX (C-1)	Outer BOX (A-7)	
мсрн3	мсрн3	3,000	15, 000	90,000	5 reels contained	6 inner boxes contained	
					Dimensions:mm (external)	Dimensions:mm (external)	
					183×72×185	440×195×210	



2. Taping configuration



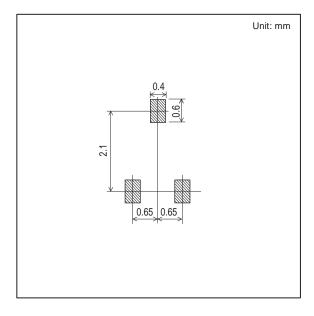


Those with pin 1 index on the feed hole side·····TL

Outline Drawing

30A02MH-TL-E, 30A02MH-TL-H

Land Pattern Example



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